



Fumitaro Ishikawa

Hokkaido University

MON Engineering Building #2

2^{ed} floor, Room E1-233

16

DEC

10:00

ACADEMIC
LECTURE

Advancing Si-Integrated GaAs Nanowires: Dilute Nitrides and Bismides, Oxidation, and Wafer-Scale Growth

Professor Ishikawa obtained his B.S. and Ph.D. from Hokkaido University. He was a Visiting Scientist at Paul Drude Institute for Solid State Electronics in Germany, and faculty members at Osaka University and Ehime University.



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